# INTEGRATED CIRCUITS



Product specification Supersedes data of 1995 Sep 06 IC23 Data Handbook

1998 Jan 16



## 74ABT244

### **FEATURES**

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- Power-up 3-State
- Live insertion capacity
- Inputs are disabled during 3-State mode

## QUICK REFERENCE DATA

## DESCRIPTION

The 74ABT244 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

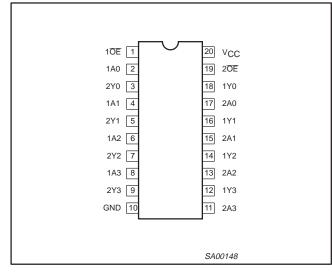
The 74ABT244 device is an octal buffer that is ideal for driving bus lines. The device features two Output Enables ( $1\overline{OE}$ ,  $2\overline{OE}$ ), each controlling four of the 3-State outputs.

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	C <sub>L</sub> = 50pF; V <sub>CC</sub> = 5V	2.9	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	4	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; $V_O = 0V$ or $V_{CC}$	7	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; $V_{CC}$ =5.5V	50	μΑ

### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	–40°C to +85°C	74ABT244 N	74ABT244 N	SOT146-1
20-Pin plastic SO	–40°C to +85°C	74ABT244 D	74ABT244 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74ABT244 DB	74ABT244 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +85°C	74ABT244 PW	74ABT244PW DH	SOT360-1

## **PIN CONFIGURATION**

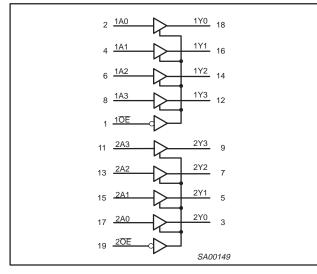


## **PIN DESCRIPTION**

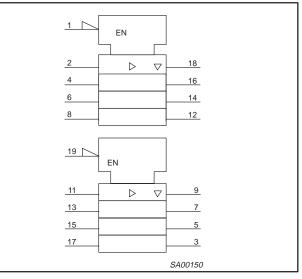
PIN NUMBER	SYMBOL	NAME AND FUNCTION			
2, 4, 6, 8	1A0 – 1A3	Data inputs			
11, 13, 15, 17	2A0 – 2A3	Data inputs			
18, 16, 14, 12	1Y0 – 1Y3	Data outputs			
9, 7, 5, 3	2Y0 – 2Y3	Data outputs			
1, 19	1 <u>0E</u> , 2 <u>0E</u>	Output enables			
10	GND	Ground (0V)			
20	V <sub>CC</sub>	Positive supply voltage			

## 74ABT244

## LOGIC SYMBOL



## LOGIC SYMBOL (IEEE/IEC)



## **FUNCTION TABLE**

	INP	OUTF	PUTS		
1 <mark>0E</mark>	1An	2 <del>0E</del> 2An		1Yn	2Yn
L	L	L	L	L	L
L	н	L	н	н	н
н	х	н	х	Z	Z

H = High voltage level

L = Low voltage level X = Don't care Z = High impedance "off" state

## **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-18	mA
VI	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
I <sub>OUT</sub>	DC output current	output in Low state	128	mA
T <sub>stg</sub>	Storage temperature range		65 to 150	°C

#### NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 74ABT244

## **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWBOL	PARAMETER	Min	Max	UNIT
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level Input voltage		0.8	V
I <sub>ОН</sub>	High-level output current		-32	mA
I <sub>OL</sub>	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

## DC ELECTRICAL CHARACTERISTICS

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Ta	<sub>mb</sub> = +25	°C	T <sub>amb</sub> =	: –40°C 85°C	UNIT
			Min	Тур	Max	Min	Max	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V
		$V_{CC}$ = 4.5V; $I_{OH}$ = -3mA; $V_I$ = $V_{IL}$ or $V_{IH}$	2.5	2.9		2.5		V
V <sub>OH</sub>	High-level output voltage	$V_{CC}$ = 5.0V; $I_{OH}$ = -3mA; $V_I$ = $V_{IL}$ or $V_{IH}$	3.0	3.4		3.0		V
		$V_{CC}$ = 4.5V; $I_{OH}$ = -32mA; $V_I$ = $V_{IL}$ or $V_{IH}$	2.0	2.4		2.0		V
V <sub>OL</sub>	Low-level output voltage	$V_{CC}$ = 4.5V; $I_{OL}$ = 64mA; $V_I$ = $V_{IL}$ or $V_{IH}$		0.42	0.55		0.55	V
l <sub>l</sub>	Input leakage current	$V_{CC} = 5.5$ V; $V_I = GND$ or 5.5V		±0.01	±1.0		±1.0	μA
I <sub>OFF</sub>	Power-off leakage current	$V_{CC}$ = 0.0V; $V_{O}$ or $V_{I}~\leq~4.5V$		±5.0	±100		±100	μA
I <sub>PU/PD</sub>	Power-up/down 3-State output current <sup>3</sup>	$V_{CC}$ = 2.0V; $V_O$ = 0.5V; $V_I$ = GND or $V_{CC}$ ; V <sub>OE</sub> = Don't care		±5.0	±50		±50	μΑ
I <sub>OZH</sub>	3-State output High current	$V_{CC}$ = 5.5V; $V_{O}$ = 2.7V; $V_{I}$ = $V_{IL}$ or $V_{IH}$		5.0	50		50	μΑ
I <sub>OZL</sub>	3-State output Low current	$V_{CC}$ = 5.5V; $V_{O}$ = 0.5V; $V_{I}$ = $V_{IL}$ or $V_{IH}$		-5.0	-50		-50	μΑ
ICEX	Output HIgh leakage current	$V_{CC}$ = 5.5V; $V_{O}$ = 5.5V; $V_{I}$ = GND or $V_{CC}$		5.0	50		50	μΑ
Ι <sub>Ο</sub>	Short-circuit output current <sup>1</sup>	$V_{CC} = 5.5 V; V_{O} = 2.5 V$	-40	-100	-180	-40	-180	mA
I <sub>CCH</sub>		$V_{CC}$ = 5.5V; Outputs High, $V_I$ = GND or $V_{CC}$		50	250		250	μΑ
I <sub>CCL</sub>	Quiescent supply current	$V_{CC}$ = 5.5V; Outputs Low, $V_{I}$ = GND or $V_{CC}$		24	30		30	mA
I <sub>CCZ</sub>		$V_{CC}$ = 5.5V; Outputs 3-State; V <sub>I</sub> = GND or V <sub>CC</sub>		50	250		250	μA
		Outputs enabled, one data input at 3.4V, other inputs at $V_{CC}$ or GND; $V_{CC} = 5.5V$		0.5	1.5		1.5	mA
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	Outputs 3-State, one data input at 3.4V, other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5V		50	250		250	μΑ
		Outputs 3-State, one enable input at 3.4V, other inputs at $V_{CC}$ or GND; $V_{CC}$ = 5.5V		0.5	1.5		1.5	mA

NOTES:

Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
This is the increase in supply current for each input at 3.4V.
This parameter is valid for any V<sub>CC</sub> between 0V and 2.1V with a transition time of up to 10msec. For V<sub>CC</sub> = 2.1V to V<sub>CC</sub> = 5V ± 10%, a transition time of up to 100µsec is permitted.

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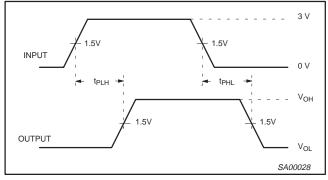
### **AC CHARACTERISTICS**

GND = 0V;  $t_R = t_F = 2.5 \text{ns}$ ;  $C_L = 50 \text{pF}$ ,  $R_L = 500 \Omega$ 

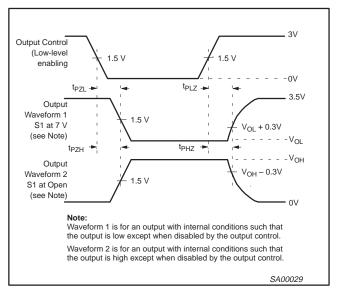
SYMBOL	PARAMETER	WAVEFORM	T <sub>a</sub> V	<sub>imb</sub> = +25° <sub>CC</sub> = +5.0	C V	$T_{amb} = -40^{\circ}$ $V_{CC} = +5.$	UNIT	
			Min	Тур	Мах	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	1	1.0 1.0	2.6 2.9	4.1 4.2	1.0 1.0	4.6 4.6	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.1 2.1	3.1 4.1	4.6 5.6	1.1 2.1	5.1 6.1	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low level	2	2.1 1.7	4.1 2.7	5.6 5.2	2.1 1.7	6.6 5.7	ns

## AC WAVEFORMS

 $V_{M}$  = 1.5V,  $V_{IN}$  = GND to 3.0V



Waveform 1. Waveforms Showing the Input (An) to Output (Yn) Propagation Delays



Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

#### 7 V 500 Ω S1 .0 From Output Open Under Test GND 500 Ω $C_L = 50 \text{ pF}$ Load Circuit TEST **S**1 t<sub>pd</sub> open 7 V t<sub>PLZ</sub>/t<sub>PZL</sub> t<sub>PHZ</sub>/t<sub>PZH</sub> open DEFINITIONS Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value. $C_L =$ SA00012

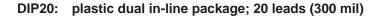
## **TEST CIRCUIT AND WAVEFORMS**

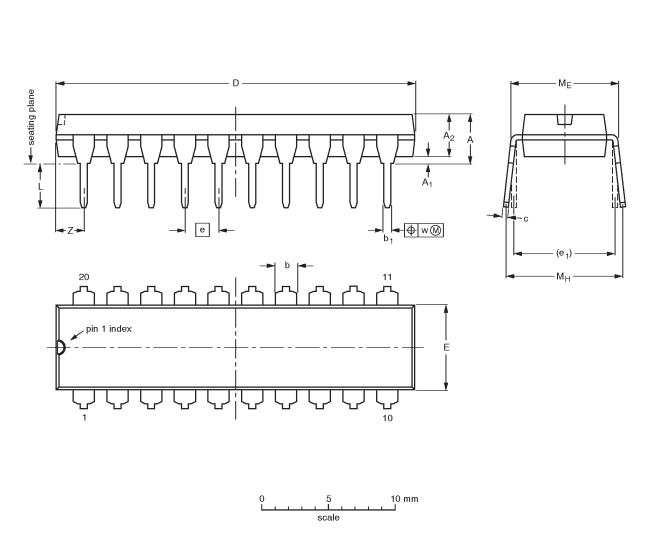
### Product specification

SOT146-1

# Octal buffer/line driver (3-State)

## 74ABT244





### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

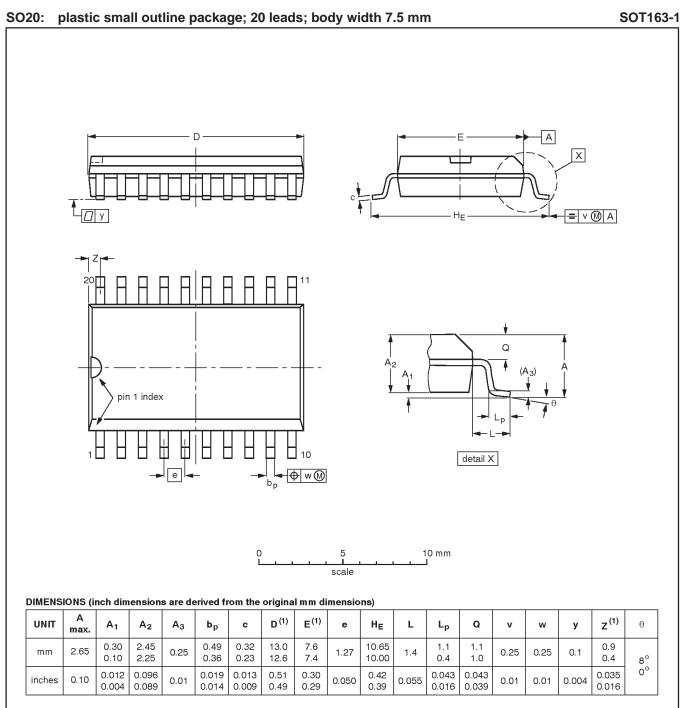
UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

ſ	OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
	VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
	SOT146-1			SC603		<del>-92-11-17</del> 95-05-24	

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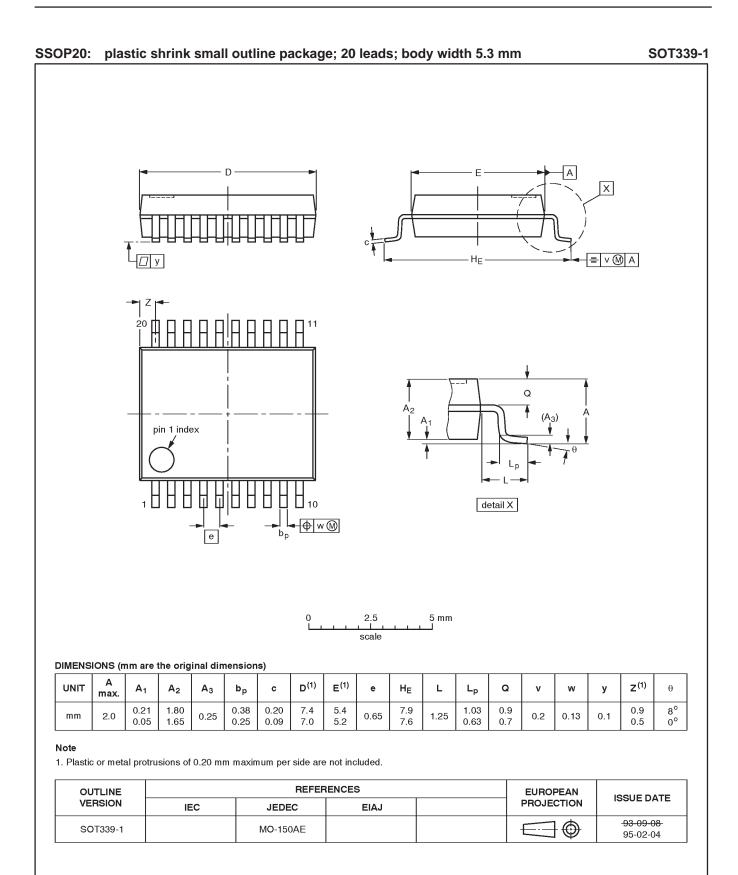


### Note

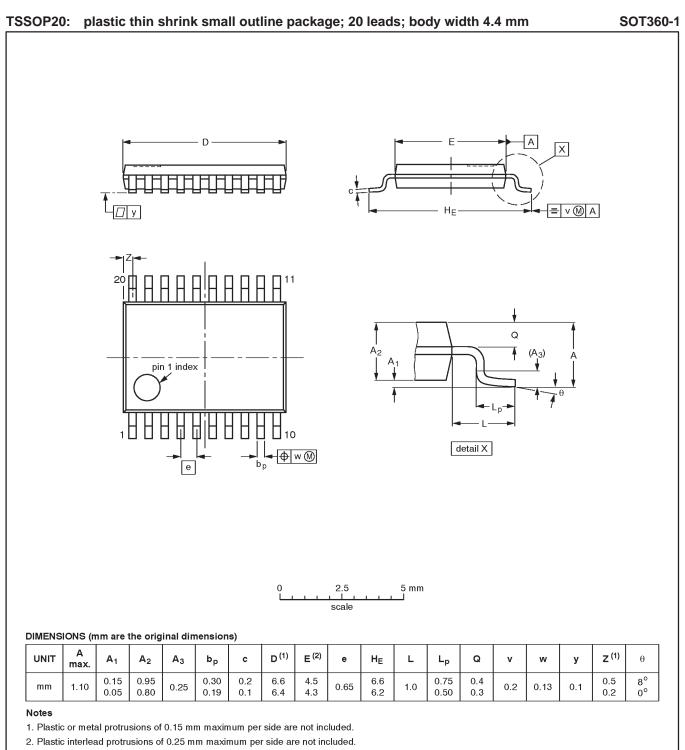
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN ISSUE DAT		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013AC			<del>-92-11-17</del> 95-01-24	

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OUTLINE		REFER	ENCES	EUROPEAN		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT360-1		MO-153AC			<del>-93-06-16</del> 95-02-04	

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### Data sheet status

Data sheet status	Product status	Definition <sup>[1]</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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